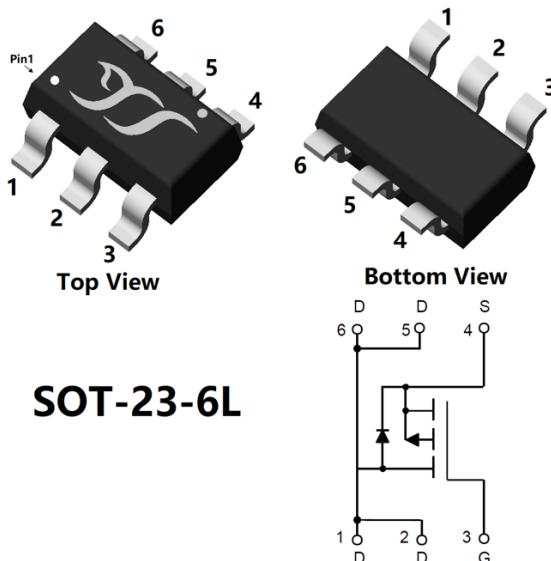


## P-Channel Enhancement Mode Field Effect Transistor


**SOT-23-6L**

### Product Summary

• $V_{DS}$	-60V
• $I_D$	-2.8A
• $R_{DS(ON)}$ (at $V_{GS}=-10V$ )	<100mΩ
• $R_{DS(ON)}$ (at $V_{GS}=-4.5V$ )	<120mΩ

### General Description

- High density cell design for Low RDS(ON)
- High Speed switching
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- PWM applications
- Power management
- Load switch

### ■ Limiting Values

Parameter	Conditions		Symbol	Min	Max	Unit
Drain-source Voltage	$T_J \geq 25^\circ C; T_J \leq 150^\circ C$		$V_{DS}$	-	-60	V
Gate-source Voltage	$T_J \leq 150^\circ C; DC$		$V_{GS}$	-20	20	
Continuous Drain Current (Note 1,2)	Steady-State	$T_A=25^\circ C, V_{GS}=-10V$	$I_D$	-	-2.8	A
		$T_A=100^\circ C, V_{GS}=-10V$		-	-1.8	
Pulsed Drain Current	$T_A=25^\circ C, t_p \leq 10\mu s$		$I_{DM}$	-	-22.4	A
Maximum Body-Diode Continuous Current	$T_A=25^\circ C$		$I_S$		-1.6	
Total Power Dissipation (Note 1,2)	Steady-State	$T_A=25^\circ C$	$P_D$	-	1.5	W
		$T_A=100^\circ C$		-	0.6	
Junction and Storage Temperature Range	$T_J, T_{STG}$			-55	150	°C

### ■ Thermal Resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	$R_{\theta JA}$	-	84	°C/W

### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJJ100P06AJ	F2	100AJ	3000	30000	120000	7" reel



# YJJ100P06AJ

## ■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A, T_j=25^\circ C$	-60	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-60V, V_{GS}=0V, T_j=25^\circ C$	-	-	-1	$\mu A$
		$V_{DS}=-60V, V_{GS}=0V, T_j=150^\circ C$	-	-	-100	
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V, T_j=25^\circ C$	-	-	$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A, T_j=25^\circ C$	-1.2	-1.7	-2.2	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-2A, T_j=25^\circ C$	-	75	100	$m\Omega$
		$V_{GS}=-4.5V, I_D=-1A, T_j=25^\circ C$	-	93	120	$m\Omega$
Diode Forward Voltage	$V_{SD}$	$I_S=-2A, V_{GS}=0V, T_j=25^\circ C$	-	-0.82	-1.2	V
Gate Resistance	$R_G$	$f=1MHz, T_j=25^\circ C$	-	5.8	-	$\Omega$
<b>Dynamic Parameters</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=-30V, V_{GS}=0V, f=1MHz, T_j=25^\circ C$	-	900	-	pF
Output Capacitance	$C_{oss}$		-	44	-	
Reverse Transfer Capacitance	$C_{rss}$		-	34	-	
<b>Switching Parameters</b>						
Total Gate Charge	$Q_g$	$V_{GS}=-10V, V_{DS}=-30V, I_D=-2A, T_j=25^\circ C$	-	18	-	nC
Gate-Source Charge	$Q_{gs}$		-	2.4	-	
Gate-Drain Charge	$Q_{gd}$		-	2.1	-	
Reverse Recovery Charge	$Q_{rr}$	$I_F=-2A, di/dt=100A/\mu s, V_{GS}=0V, V_R=-30V, T_j=25^\circ C$	-	16	-	nC
Reverse Recovery Time	$t_{rr}$		-	17	-	ns
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-10V, V_{DS}=-30V, I_D=-2A, R_L=15\Omega, R_{GEN}=3\Omega, T_j=25^\circ C$	-	6.7	-	ns
Turn-on Rise Time	$t_r$		-	3	-	
Turn-off Delay Time	$t_{D(off)}$		-	28	-	
Turn-off Fall Time	$t_f$		-	5.6	-	

Note:

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- The value of  $R_{QJA}$  is measured with the device mounted on the 40mm\*40mm\*1.1mm single layer FR-4 PCB board with 1 in<sup>2</sup> pad of 2oz. Copper, in the still air environment with  $T_A=25^\circ C$ . The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- Thermal resistance from junction to soldering point (on the exposed drain pad)

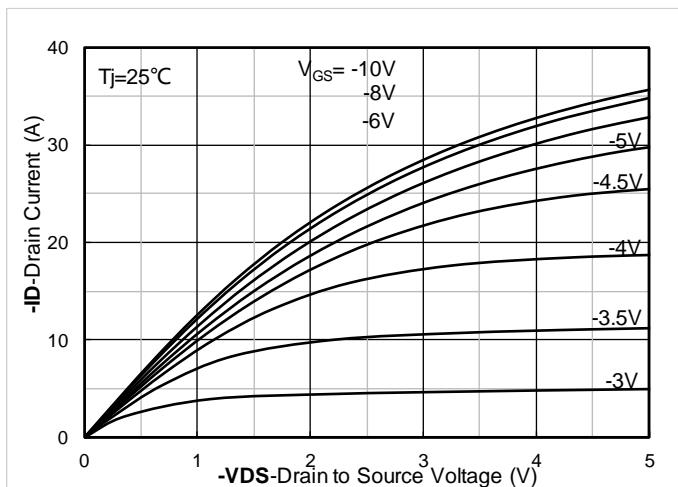
**■Typical Electrical and Thermal Characteristics Diagrams**

Figure 1. Output Characteristics; typical values

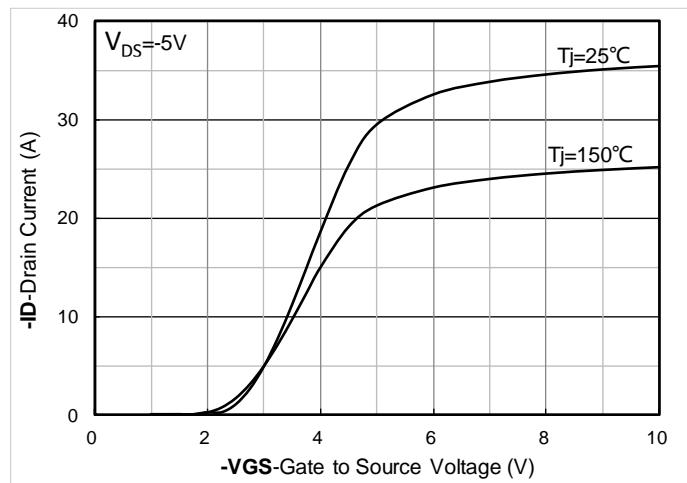


Figure 2. Transfer Characteristics; typical values

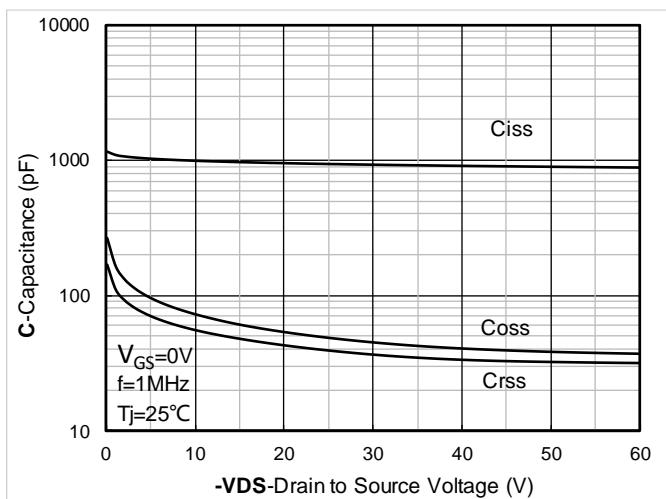


Figure 3. Capacitance Characteristics; typical values

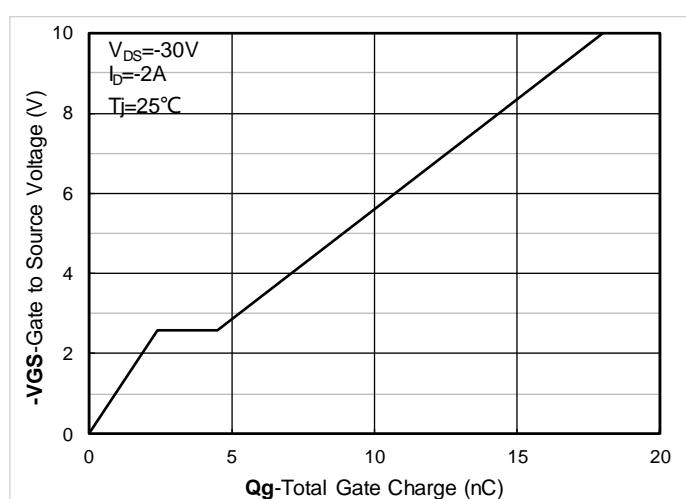


Figure 4. Gate Charge; typical values

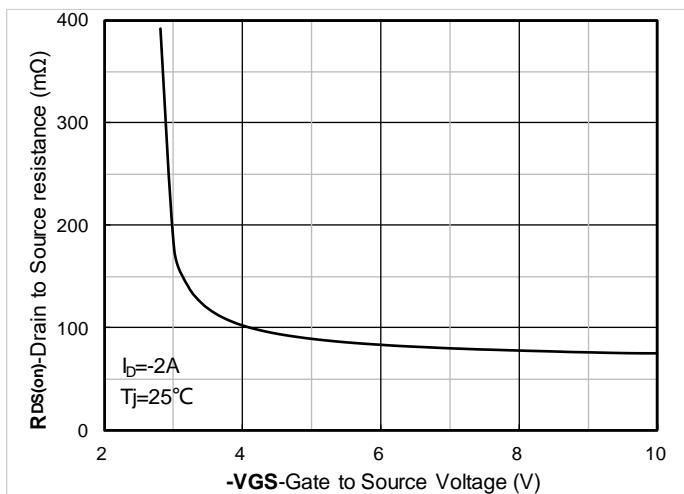


Figure 5. On-Resistance vs Gate to Source Voltage; typical values

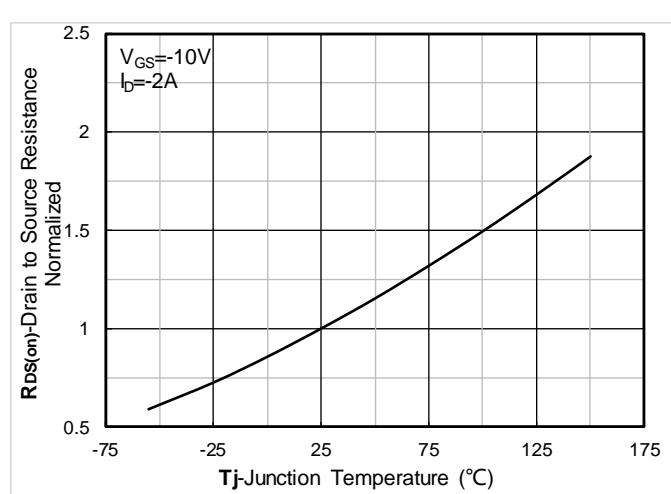


Figure 6. Normalized On-Resistance

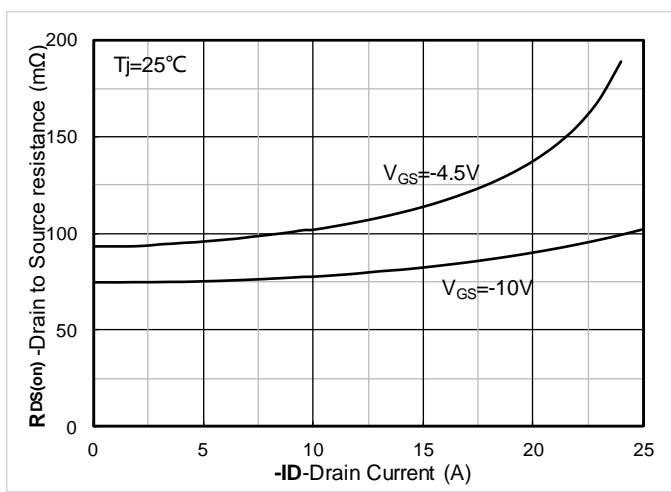


Figure 7. RDS(on) VS Drain Current; typical values

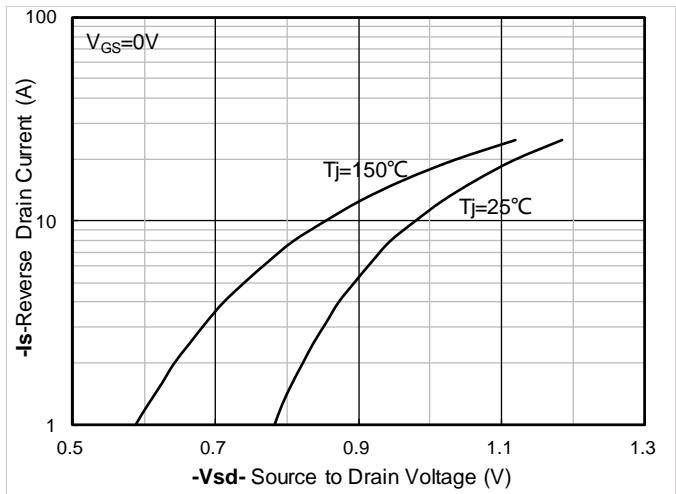


Figure 8. Forward characteristics of reverse diode; typical values

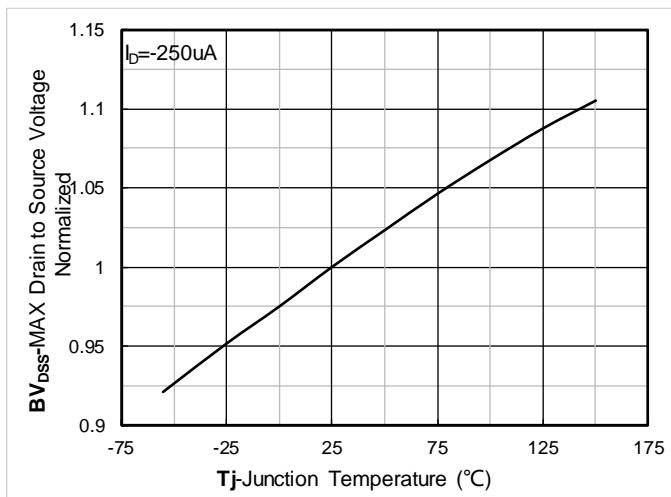


Figure 9. Normalized breakdown voltage

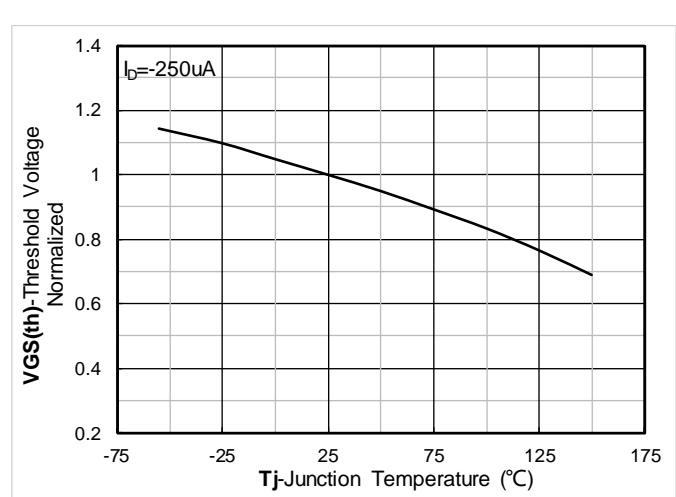


Figure 10. Normalized Threshold voltage

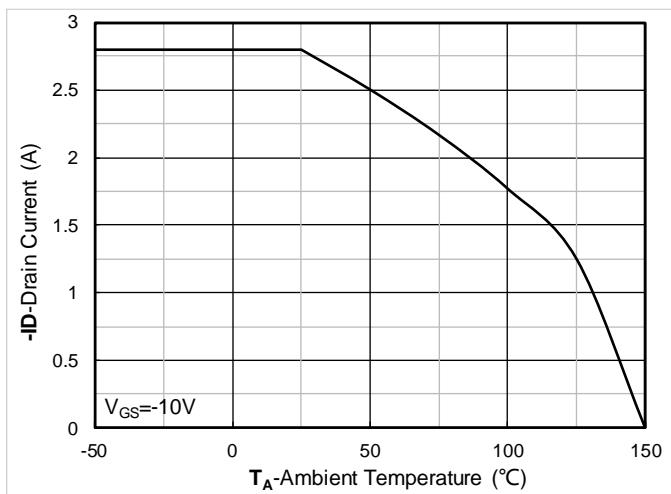


Figure 11. Current dissipation

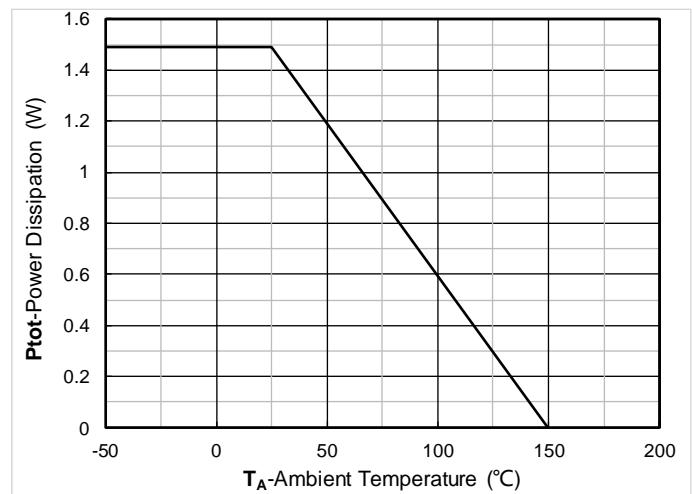


Figure 12. Power dissipation

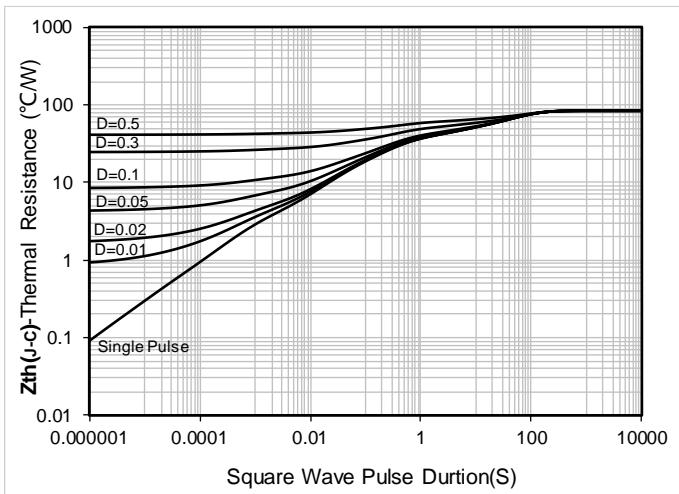


Figure 13. Maximum Transient Thermal Impedance

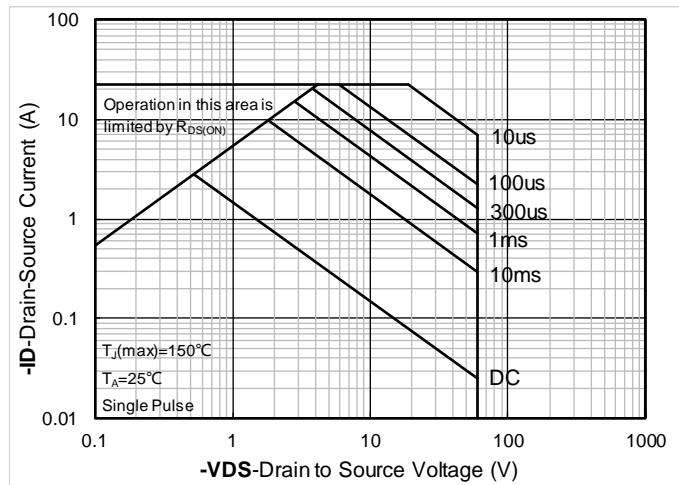
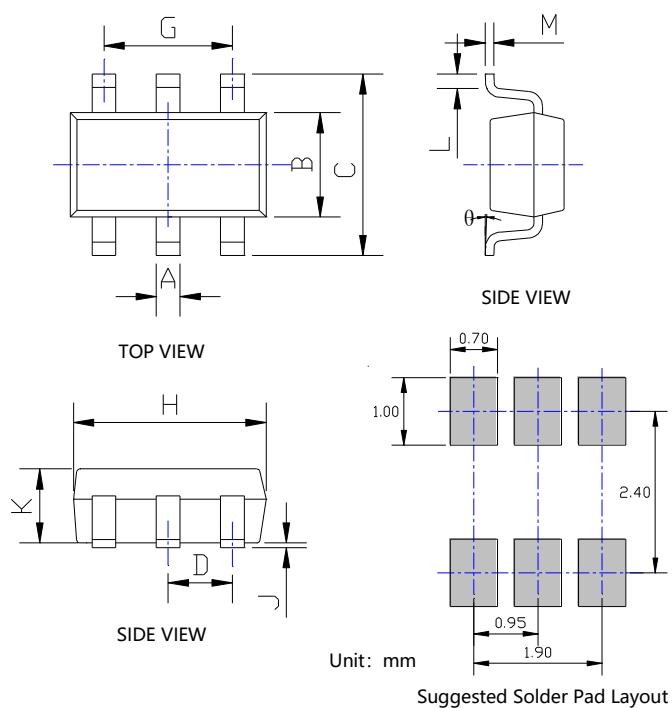


Figure 14. Safe Operation Area



## ■ SOT-23-6L Package information



SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.012	0.020	0.300	0.500
B	0.059	0.067	1.500	1.700
C	0.104	0.116	2.650	2.950
D	0.037BSC		0.950BSC	
G	0.075BSC		1.900BSC	
H	0.111	0.119	2.820	3.020
J	0.000	0.004	0.000	0.100
K	0.041	0.045	1.050	1.150
L	0.012	0.024	0.300	0.600
M	0.004	0.008	0.100	0.200
θ	0°	8°	0°	8°

## Note:

1. Controlling dimension: in millimeters.
2. General tolerance: +/-0.05mm.
3. The pad layout is for reference purposes only.



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